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Thermodynamic calculation of the In–Sn–Zn ternary system

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Abstract

A thermodynamic description of the In–Sn–Zn ternary system, which is of technical importance to optimize lead-free solder alloys, is presented using the CALPHAD method. Phase equilibria, such as isothermal and vertical sections, liquidus projection and mole fractions of the phase constitution, and thermochemical quantities were calculated and compared with the experimental data. They are in excellent agreement in most cases. \circ 2001 Elsevier Science B.V. All rights reserved.

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alternative lead-free solder alloys due to the environmental on 40 ternary alloys, Xie et al. [5] constructed three cross and health concerns on lead usage. Among many potential sections with constant Sn to Zn ratio of 2:1, 1:1 and 1:2, as substitutes, Sn–Zn-based alloys were viewed as very well as one with 10 at.% In. promising candidates [1]. Recently, MacCormack et al. [2] Moser [6] determined the thermodynamic properties of demonstrated that the addition of In into the Sn–Zn alloys dilute liquid zinc solutions of the In–Sn–Zn system by can positively contribute to the wetting characteristics of means of the emf method at 714, 757 and 805 K, the alloys and lower sufficiently their melting tempera- respectively. Most recently, performing on a Calvet type tures. Furthermore, a solder alloy, Sn 86%, In 5%, Zn 9% drop calorimeter, Fiorani et al. [7] investigated the en- (wt.), with sufficient similar melting points to the eutectic thalpy of mixing of the In–Sn–Zn liquid homogeneous Pb–Sn solders, was developed and proved experimentally phase following three isopletic cuts, i.e. In:Sn=In:Zn= as a drop-in replacement for the traditional Pb–Sn solders. Sn: $Zn=1:1$, as a border ternary system of the In–Pb–Sn– Accordingly, an appropriate thermodynamic description of Zn quaternary system. the In–Sn–Zn ternary system is desirable to design and The aim of this work is to critically evaluate the optimize the composition and microstructure of the alloys. previous works and develop a set of parameters of the

both phase relation and thermodynamic properties of the which is one of our serial studies on the thermodynamic In–Sn–Zn system. Spengler [3] reported his pioneering database for the micro-soldering alloys including the study in 1954, where an entire, but primary, liquidus elements of Pb, Bi, Sn, Sb, Cu, Ag, Zn and In [8,9]. projection was constructed. Recently, MacCormack and Jin [1,2] studied the melting behavior of two ternary alloys, Sn 86%, In 5%, Zn 9% and Sn 81%, In 10%, Zn 9% (wt.), and **2. Evaluation of previous works** reported their melting points were 188 and 178°C, respectively. More recently, Yoon et al. [4] analyzed several 2.1. *Experimental data of the ternary system* specific ternary alloys by differential scanning calorimetry (DSC) measurement, supplemented by scanning electron As regards the exploring work by Spengler [3], only the

Many investigations contributed to the determination of In–Sn–Zn ternary system using the CALPHAD method,

microscopy (SEM) and X-ray diffractometry (XRD). Two accessible experimental points on the ternary eutectic partial vertical sections and the liquidus projection were reaction, rather than the graphical liquidus surface, were adopted in this work. Although the number of alloys *Corresponding author. analyzed by Ref. [2] was too few to determine any phase

^{1.} Introduction subsequently constructed combining a primary thermodynamic calculation and the experimental results. Later on, Over several years, much effort was put into developing in a DTA lattice parameter and micro-probe measurement

and 6 wt.% Zn. These two sections are critical to evaluate also employed to adjust the parameters of the liquid phase. and optimize the In–Sn–Zn solders in service. The following section will recalculate them and make a comparison 2.2. *Assessment of the binary systems* between them with their respective former versions.

The study by Xie et al. [5] was visualized as the most

Lee et al. [10,11] have assessed three binary systems,

extensive and elaborate work on this system up to now. All

there data were thus accepted in this work. Howev melting temperature solders research, all the cooling data were also given a relative low weight.

Moser [6] determined the activities of Zn in the dilute **3. Thermodynamic model and optimization procedure** alloys solution at 3, 5, 7 and 10 at.% Zn. But all the experimental values were just marked in small charts The substitutional solution model was used to describe

assessment, i.e. the introduction of In in the Sn–Zn alloys taken into account in this work, although his data were can effectively lower their melting points. generally regarded as quite reliable. The enthalpies of Yoon et al. [4] reported two partial cross sections with 9 mixing of the liquid phase due to Fiorani et al. [7] were

Table 1

Summary of the parameters assessed in the present work and the binary parameters from the selected literature (values for solution phases are given in J/mol of atoms)

System	Phase	Parameters	Ref.
$In-Sn$	Liquid	${}^{0}L_{\text{In,Sn}}^{\text{liquid}} = -711 - 1.6934 \times T$	$[10]$
	$Bct-(Sn)$	$L_{\text{In,Sn}}^{\text{liquid}} = -64 - 1.3592 \times T$ $L_{\text{In,Sn}}^{\text{beta}} = -239 + 2.8509 \times T$	[10]
	$Tet-(In)$	${}^{0}L_{\text{In,Sn}}^{\text{tet-}(1n)} = +743 - 3.3139 \times T$	[10]
		$L_{\text{In,Sn}}^{\text{tet-(In)}} = -1487$	
	γ	${}^{0}G_{\text{In}}^{\gamma}$ = +GHSERIN + 10 292.5 – 7.64 $\times T$	
		${}^{0}G_{\text{Sn}}^{\gamma}$ = +GHSERSN + 925.3 – 1.7562 $\times T$	[10]
		${}^{0}L_{\text{In,Sn}}^{\gamma}$ = -15 715.5 + 19.3402 × T	
	β	${}^{0}G_{\text{In}}^{\beta}$ = +GHSERIN	
		${}^{0}G_{\text{Sn}}^{B}$ = +GHSERSN + 5015.5 – 7.5 × T	[10]
		${}^{0}L_{\text{In,Sn}}^{\beta} = -235 - 3.6954 \times T$	
$In-Zn$	Liquid	${}^{0}L_{\text{In,Zn}}^{\text{liquid}} = +12\,401 - 4.4498 \times T$	
		$^{1}L_{\text{In,Zn}}^{\text{liquid}} = -3186 + 1.756 \times T$	[11]
	$Tet-(In)$	${}^{2}L_{\text{In,Zn}}^{\text{liquid}}$ = 679 ${}^{0}L_{\text{In,Zn}}^{\text{tet-ln}}$ = +4430 - 4.4498 × T	[11]
	$Hep-(Zn)$	$1_{\text{Lie-}(1n)}^{1 \text{Ex}} = 9717$ $0_{\text{Lip.}(2n)}^{1 \text{Ex}} = 23114$ $0_{\text{Lsp.}(2n)}^{1 \text{Ex}} = +12710 - 9.162 \times T$	[11]
$Sn-Zn$	Liquid		
		${}^{1}L_{\text{Sn,Zn}}^{\text{liquid}} = -5360 + 3.45 \times T$	[13]
	$Bct-(Sn)$	$2 \lim_{\substack{S_{\rm R,Zn} \to 0 \text{b} \to 0}} 2 \lim_{\substack{S_{\rm R,Zn} \to 0 \text{b} \to 0}} 835$ $0 \lim_{\substack{S_{\rm R,Zn} \to 0 \text{b} \to 0 \text{c} \to 0}} 9260$ $0 \lim_{\substack{S_{\rm R,Zn} \to 0 \text{b} \to 0 \text{c} \to 0}} 6000$ $0 \lim_{\substack{S_{\rm R,Zn} \to 0 \text{b} \to 0 \text{c} \to 0}} 6 \text{HSERSN} + 2400$	$[13]$
	$Tet-(Sn,Zn)$		This work
	$Hep-(Zn)$		$[13]$
		${}^{0}G_{\text{Sn,Zn}}^{\text{nep-(Zn)}} = 40\,000$	
$In-Sn-Zn$	Liquid	${}^{0}L_{\text{In,Sn,Zn}}^{\text{liquid}} = -2001 - 3.61 \times T$	
		${}^{1}L_{\text{In,Sn,Zn}}^{\text{liquid}} = 832 - 4.2 \times T$	This work
		$^{2}L_{\text{In,Sn,Zn}}^{\text{liquid}} = -16\,257 + 21.2 \times T$	

all the phases in the system. The model yields the following expression for the Gibbs energy:

$$
G_m = x_{\text{In}}{}^{\circ}G_{\text{In}} + x_{\text{Sn}}{}^{\circ}G_{\text{Sn}} + x_{\text{Zn}}{}^{\circ}G_{\text{Zn}} + RT(x_{\text{In}}\ln x_{\text{In}} + x_{\text{Sn}}\ln x_{\text{Sn}} + x_{\text{Zn}}\ln x_{\text{Zn}}) + {}^{\text{ex}}G_m.
$$
 (1)

The parameter ${}^{\circ}G_i$ is the Gibbs energy of pure component *i* which was taken from the database [14] or the accepted binary systems. The excess energy \mathfrak{G}_m can be derived from the binary excess Gibbs energy $e^{i\theta x}G_{i,j}$ (*i*, $j=In$, Sn and Zn) using the Muggianu extrapolation model [15]:

$$
{}^{\text{ex}}G_m = \sum_{i=1}^{2} \sum_{j=i+1}^{3} [x_i x_j / (V_{i,j} \cdot V_{j,i})] \cdot {}^{\text{ex}}G_{i,j} + x_{\text{In}} x_{\text{Sn}} x_{\text{In}} (V_{\text{In}} L_{\text{In}} + x_{\text{Sn}} L_{\text{Sn}} + x_{\text{Zn}} L_{\text{Zn}}). \tag{2}
$$

 L_i denotes ternary interaction parameter, the terms $V_{i,i}$ and $V_{i,i}$ are represented by:

$$
V_{i,j} = \frac{1 + x_i - x_j}{2} \text{ and } V_{j,i} = \frac{1 + x_j - x_i}{2}.
$$
 (3)

The optimization of parameters was carried out using the Parrot module in the Thermo-Calc program developed ters were introduced to β and γ with lack of the confirmed data. It is to emphasize that, no ternary compound parame- and one for tetragonal.

Fig. 2. Calculated partial mixing enthalpies of In and Sn in liquid at 720 and 756 K, following the isopletic cuts $\text{Sn:Zn}=1:1$ and $\text{In:Zn}=1:1$, respectively.

by Sundman et al. [16]. At first, two sets of the experimen- ternary homogeneity ranges. It was also found, during the tal thermodynamic data [6,7] were taken into account to optimization, only a metastable binary regular parameter,
simultaneously optimize the ternary interaction parameters ${}^{0}L_{\text{Sn,Zn}}^{tot}$, is inevitably required to sa most of the experimental data. As a result, only four phases were then optimized by fitting the phase diagram parameters were employed in this work, i.e. three for liquid

Fig. 1. Calculated activity coefficient of Zn in the liquid phase with 3 at.% Zn at 714, 757 and 805 K, respectively, compared with the Fig. 3. The comparison between the calculated partial mixing enthalpy of experimental data.
 Example 12 Zn in liquid with In:Sn = 1:1 at 720 K and the experimental data.

Table 1, as well as the accepted binary parameters of the nicely with the data from Ref. [7], but for the fact all are

Fig. 1 illustrates the comparison between the calculated presented in Figs. 2 and 3. activity coefficient of Zn in liquid and the experimental Fig. 4a–c show excellent agreements between the data [6] at 714, 757 and 805 K with 3 at.% Zn. It is calculated vertical sections and the experimental data at

4. Results and discussion obvious that the agreement is very satisfactory with reference to the experimental data of a certain scatter in the The parameters assessed in this work are summarized in middle In contents. The calculation does not compare so In–Sn [10], In–Zn [11] and Sn–Zn system [13]. indeed within the claimed experimental uncertainty, as

Fig. 4. Calculated vertical sections of the In–Sn–Zn ternary system at: (a) $Sn:Zn=2:1$; (b) $Sn:Zn=1:1$; and (c) $Sn:Zn=1:2$ in comparison with the experimental data.

 $Sn:Zn=2:1$, 1:1 and 1:2, respectively. As already explained in Section 2, no further attempt was made to better fit the heating data at the low zinc content, as well as all the cooling data. Fig. 5 gives a full computed representation of the determined vertical sections with the constant 10 at.% In [5]. Although the present results cannot also replicate two single γ phase alloys (Sn 80%, In 10%, Zn 10% and Sn 65%, In 10%, Zn 25% (at.)) well, however, they could derive a more reasonable phase relation compared with those by Xie et al. $A \gamma + [Sn] + [Zn]$ three-phase region was newly confirmed to locate at the low temperature; such a phase distribution is fully in accord with the binary information. The deficient section by Xie et al. is clearly due to an overlook of the $[In]+ \gamma$ two-phase region.

Fig. 6a and b represent the calculated vertical sections with the constant 9 and 6 wt.% Zn, respectively. As shown in the figures, the calculated liquidus exhibits a large discrepancy with the experimental values. A similar reason as for the heating data from Xie et al. should be expected to hold for this case. The present work also supported that the Sn 81%, In 10%, Zn 9% (wt.) alloy falls within the $[Zn] + \gamma$ two-phase field at 160°C confirmed by the XRD measurement [4]. Additionally, to give a full representation of phase relation, Fig. 7a and b show two predicted isothermal sections of the In–Sn–Zn system at 100° C and 200° C, respectively. These two figures undoubtedly suggest, together with Fig. 6a and b, the optimum indium concentration for an In–Sn–Zn base solder is around 2–5 wt.%, since a favored simple microstructure without the γ phase, in essence, is achievable.

The calculated liquidus projection of the In–Sn–Zn ternary system is presented in Fig. 8a. Fig. 8b provides detailed information at the Sn-rich corner, which clearly

Fig. 6. Calculated vertical sections of the In–Sn–Zn ternary system at: (a) 9 wt.% Zn; (b) 6 wt.% Zn in comparison with the experimental data.

indicates the zinc-rich side of the eutectic should be avoided because the liquidus temperature increases significantly with increasing zinc concentration. Table 2 lists the calculated invariant reactions including observed ternary invariant equilibria. It can be seen from it that the ternary eutectic reaction (E) is calculated to occur at the composition of Sn 46.2%, In 52.2%, Zn 1.6% (wt.) at 107° C, which compares well to the experimentally re-Fig. 5. Calculated vertical section of the In–Sn–Zn ternary system at 10 ported Sn 46.0%, In 52.2%, Zn 1.8% (wt.) at 108°C [3]. It at.% In in comparison with the experimental data. is interesting to find that the invariant temperature of U1 is

Fig. 7. Calculated isothermal section of the In–Sn–Zn ternary system at: (a) 100° C and (b) 200° C.

Table 2

Fig. 8. (a) The entire calculated liquidus projection of the In–Sn–Zn ternary system; (b) an enlarged portion at the Sn-rich corner.

 (b)

 0.30

Fig. 9. Calculated phase fractions of alloy U1 during cooling following: (a) the Level rule and (b) Scheil calculation. Fig. 10. Calculated e1–U1 cross section of the In–Sn–Zn ternary system.

very close to the Pb–Sn eutectic temperature. As a of a large phase fraction in case of attainment of equilibconsequence, in Fig. 9a, the phase fractions of alloy U1 rium in service. In a more detailed inspiration, Scheil during cooling were calculated following the Level rule. calculation was carried out for this alloy, as shown in Fig. Obviously, it indicates that this alloy is far from a suitable 9b. In comparison to the Level rule, this model describes solder even though it has a favored melting temperature, another limiting case; it assumes that no back diffusion because it would contain the undesirable soft compound γ occurs in the solid state and perfect mixing in the liquid phase. For most alloys, however, Scheil calculation can still provide a prediction close to reality. It is noted that the formation of ternary eutectic due to segregation in the Scheil model solidification drastically increases the freezing range. Quite the contrary, a critical practical requirement for solders is a limited freezing range.

> To investigate the effect of added In on the Sn–Zn eutectic alloys in more depth, the e1–U1 cross section was calculated in Fig. 10. It is obvious that the binary Sn–Zn eutectic reaction is suitably depressed with the increase of In until the ternary peritectic reaction U1 is reached. Comparing with the vertical section at 9 wt.% Zn in Fig. 6a, a very similar phase relation can be found in Fig. 10. It should be emphasized that, however, their respective effects of added In on the liquidus temperature and the freezing range are remarkably different; the incorporation of In increases the liquidus temperature and the temperature range of two- or three-phase field including liquid at 9 wt.% Zn, while decreaseing both features in the cross section of e1–U1. These facts suggest that the alloys within the range of 2–5 wt.% located at the e1–U1 line, characterized by their similar melting behavior to that of Sn–Pb eutectic alloys, are more suitable for the lead-free solders rather than the Sn 89–86%, Zn 9%, In 2–5% (wt.) alloys. These findings are different to the conclusion in Fig. 8b, but equally satisfactory in results, which are important for use in the design of new solder alloys.

Fig. 11. The reaction scheme of the In–Sn–Zn ternary system.

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A thermodynamic description of the In-Sn-Zn ternary
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cases. The present calculation can serve as a basic knowl-
edge to design and optimize Sn-Zn-based solder alloys
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